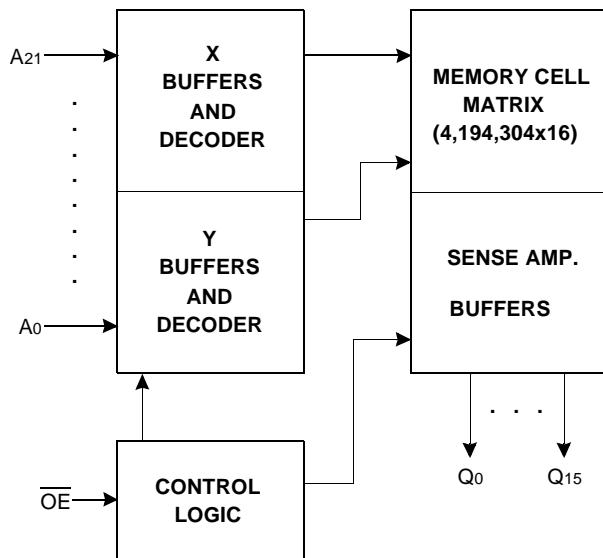


## 64M-Bit (4Mx16) CMOS MASK ROM

### FEATURES

- 4,194,304 x 16 bit organization
- Fast access time :
  - 100ns(Max.) : CL=50pF
  - 120ns(Max.) : CL=100pF
- Supply voltage : single +5V
- Current consumption
  - Operating : 70mA(Max.)
- Fully static operation
- All inputs and outputs TTL compatible
- Three state outputs
- Package
  - K3N7C4000C-DC : 42-DIP-600

### FUNCTIONAL BLOCK DIAGRAM



Pin Name	Pin Function
A0 - A21	Address Inputs
Q0 - Q15	Data Outputs
OE	Output Enable
Vcc	Power (+5V)
Vss	Ground

### GENERAL DESCRIPTION

The K3N7C4000C-DC is a fully static mask programmable ROM organized 4,194,304 x 16 bit. It is fabricated using silicon-gate CMOS process technology.

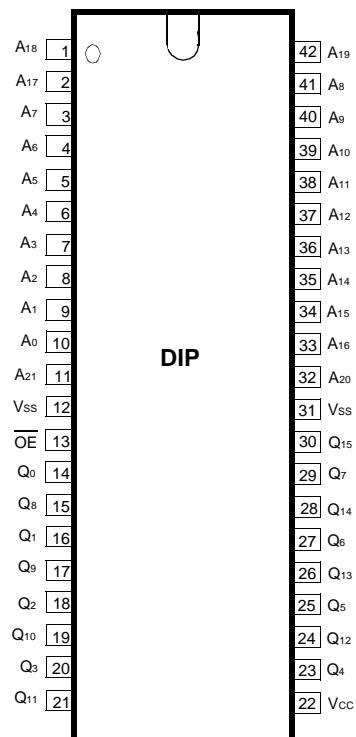
This device operates with a 5V single power supply, and all inputs and outputs are TTL compatible.

Because of its asynchronous operation, it requires no external clock assuring extremely easy operation.

It is suitable for use in program memory of microprocessor and data memory, character generator.

The K3N7C4000C-DC is packaged in a 42-DIP.

### PIN CONFIGURATION



K3N7C4000C-DC

**ABSOLUTE MAXIMUM RATINGS**

Item	Symbol	Rating	Unit
Voltage on Any Pin Relative to Vss	VIN	-0.3 to +7.0	V
Temperature Under Bias	TBIAS	-10 to +85	°C
Storage Temperature	TSTG	-55 to +150	°C

**NOTE :** Permanent device damage may occur if "ABSOLUTE MAXIMUM RATINGS" are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**RECOMMENDED OPERATING CONDITIONS**(Voltage reference to Vss, TA=0 to 70°C)

Item	Symbol	Min	Typ	Max	Unit
Supply Voltage	Vcc	4.5	5.0	5.5	V
Supply Voltage	Vss	0	0	0	V

**DC CHARACTERISTICS**

Parameter	Symbol	Test Conditions	Min	Max	Unit
Operating Current	Icc	Cycle=5MHz, all outputs open OE=VIL, VIN=0.6V to 2.4V (AC Test Condition)	-	70	mA
Input Leakage Current	ILI	VIN=0 to Vcc	-	10	µA
Output Leakage Current	ILO	VOUT=0 to Vcc	-	10	µA
Input High Voltage, All Inputs	VIH		2.2	Vcc+0.3	V
Input Low Voltage, All Inputs	VIL		-0.3	0.8	V
Output High Voltage Level	VOH	IOH=-400µA	2.4	-	V
Output Low Voltage Level	VOL	IOL=2.1mA	-	0.4	V

**NOTE :** Minimum DC Voltage(VIL) is -0.3V an input pins. During transitions, this level may undershoot to -2.0V for periods <20ns.

Maximum DC voltage on input pins(VIH) is Vcc+0.3V which, during transitions, may overshoot to Vcc+2.0V for periods <20ns.

**MODE SELECTION**

OE	Mode	Data	Power
H	Operating	High-Z	Active
L	Operating	Dout	Active

**CAPACITANCE**(TA=25°C, f=1.0MHz)

Item	Symbol	Test Conditions	Min	Max	Unit
Output Capacitance	COUT	VOUT=0V	-	12	pF
Input Capacitance	CIN	VIN=0V	-	12	pF

**NOTE :** Capacitance is periodically sampled and not 100% tested.



AC CHARACTERISTICS( $T_A=0^\circ\text{C}$  to  $+70^\circ\text{C}$ ,  $V_{CC}=5\text{V}\pm10\%$ , unless otherwise noted.)

## TEST CONDITIONS

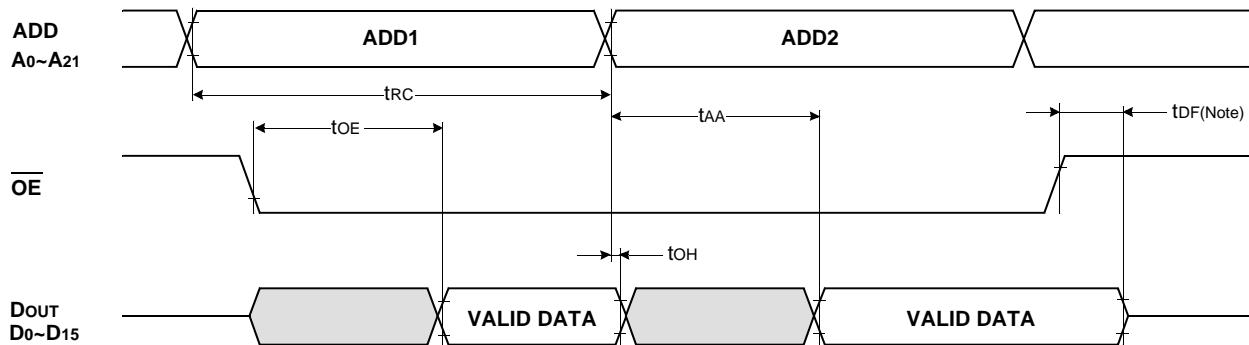
Item	Value
Input Pulse Levels	0.6V to 2.4V
Input Rise and Fall Times	10ns
Input and Output timing Levels	0.8V and 2.0V
Output Loads	1 TTL Gate and $C_L=50\text{pF}$ or $100\text{pF}$

## READ CYCLE

Item	Symbol	K3N7C4000C-DC10 ( $C_L=50\text{pF}$ )		K3N7C4000C-DC12 ( $C_L=100\text{pF}$ )		K3N7C4000C-DC15 ( $C_L=100\text{pF}$ )		Unit
		Min	Max	Min	Max	Min	Max	
Read Cycle Time	t <sub>RC</sub>	100		120		150		ns
Address Access Time	t <sub>AA</sub>		100		120		150	ns
Output Enable Access Time	t <sub>OE</sub>		50		60		70	ns
Output Disable to Output High-Z	t <sub>DF</sub>		20		20		30	ns
Output Hold from Address Change	t <sub>OH</sub>	0		0		0		ns

## TIMING DIAGRAM

## READ



NOTE : t<sub>DF</sub> is defined as the time at which the outputs achieve the open circuit condition and is not referenced to V<sub>OH</sub> or V<sub>OL</sub> level.